

# RoHS ES1A THRU ES1M

SMA/DO-214AC

0.180(4.57)

0.160(4.06)

0.110 (2.79)

0.086 (2.18)

0.067 (1.70)

0.051 (1.29)

## ES1A THRU ES1M

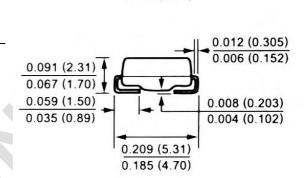
### SURFACE MOUNTED SUPER FAST RECTIFIER VOLTAGE: 50 TO 1000V CURRENT: 1.0A

#### Features

- Glass passivated junction chip
- ◆ For surface mounted application
- Low profile package
- Built-in strain relief
- High surge capability
- High temperature soldering guaranteed 250°C/10sec/at terminal/complete device
- Superfast recovery time for high efficiency

#### Mechanical data

- Cases: Molded with UL-94 class V-0 recognized Flame Retardant Epoxy
- Terminals: Plated axial leads solderable MIL-STD 202E, method 208C
- Polarity: Color band denote cathode end
- ♦ Weight:0.002 ounce, 0.064 gram





#### Maximum ratings and electrical characteristics

Ratings at  $25^{\circ}$ C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	ES1A	ES1B	ES1D	ES1G	ES1J	ES1K	ES1M	Units
Maximum recurrent peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	550	700	V
Maximum DC blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 3/8" lead length at $T_L$ =100 $^\circ$ C	I <sub>F(AV)</sub>	1.0							А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30.0							А
Maximum instantaneous forward voltage at rated forward current	VF	0.95 1.3					1	.7	V
Maximum DC reverse current Ta=25°C		10.0							μA
At rated DC blocking voltage Ta=125 $^\circ\!\!\!\mathrm{C}$	I <sub>R</sub>	100.00							μA
Maximum Reverse Recovery Time	Trr	35							nS
Typical junction capacitance	CJ	20.0							pF
Typical thermal resistance	R <sub>JA</sub>	60.0							°C/W
Storage and operating junction temperature	T <sub>STG</sub>	-50 to +150						°C	

Notes: 1. Measured at 1.0MHz and applied voltage of 4.0Vdc

2. Thermal resistance from junction to terminal mounted on  $5 \times 5$ mm copper pad area

3. Reverse recovery condition If=1.0A,Irr=0.25A